

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

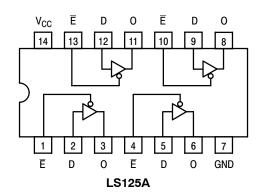
Quality Overview

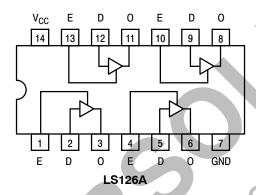
- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

Quad 3-State Buffers





TRUTH TABLES

LS125A

|--|

INP	UTS	
E	D	ОИТРИТ
L	L	-
L	Н	Н
Η	Х	(Z)
		•

ν.			
	INP	UTS	
	Е	ם	OUTPUT
	H	٦	7
	Н	H	H
	L	X	(Z)

L = LOW Voltage Level H = HIGH Voltage Level X = Don't Care

(Z) = High Impedance (off)

GUARANTEED OPERATING RANGES

Symbol	Symbol Parameter		Тур	Max	Unit
V _{CC}	Supply Voltage		5.0	5.25	V
T _A	T _A Operating Ambient Temperature Range		25	70	°C
I _{OH} Output Current – High				-2.6	mA
I _{OL} Output Current – Low				24	mA



ON Semiconductor™

http://onsemi.com

LOW POWER SCHOTTKY



N SUFFIX CASE 646



SOIC **D SUFFIX** CASE 751A



SOEIAJ M SUFFIX CASE 965

ORDERING INFORMATION

Package	Shipping
14 Pin DIP	2000 Units/Box
SOIC-14	55 Units/Rail
SOIC-14	2500/Tape & Reel
SOEIAJ-14	See Note 1
SOEIAJ-14	See Note 1
14 Pin DIP	2000 Units/Box
SOIC-14	55 Units/Rail
SOIC-14	2500/Tape & Reel
SOEIAJ-14	See Note 1
SOEIAJ-14	See Note 1
	14 Pin DIP SOIC-14 SOEIAJ-14 SOEIAJ-14 14 Pin DIP SOIC-14 SOIC-14 SOEIAJ-14

^{1.} For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

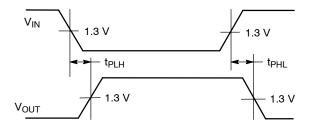
DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter		Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Ir All Inputs	nput HIGH Voltage for
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Ir All Inputs	nput LOW Voltage for
V _{IK}	Input Clamp Diode Voltage	ı		-0.65	-1.5	V	V _{CC} = MIN, I _{II}	_N = –18 mA
V _{OH}	Output HIGH Voltage		2.4			V	V _{CC} = MIN, I _C or V _{IL} per Trut	_{oH} = MAX, V _{IN} = V _{IH} th Table
	V _{OL} Output LOW Voltage			0.25	0.4	٧	I _{OL} = 12 mA	V _{CC} = V _{CC} MIN,
V _{OL}				0.35	0.5	V	I _{OL} = 24 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table
I _{OZH}	Output Off Current HIGH				20	μА	V _{CC} = MAX, \	/ _{OUT} = 2.4 V
I _{OZL}	Output Off Current LOW				-20	μΑ	V _{CC} = MAX, \	/ _{OUT} = 0.4 V
	L				20	μΑ	V _{CC} = MAX, \	/ _{IN} = 2.7 V
I _{IH}	Input HIGH Current				0.1	mA	V _{CC} = MAX, λ	$I_{1N} = 7.0 \text{ V}$
I _{IL}	Input LOW Current				-0.4	mA	V _{CC} = MAX, \	/ _{IN} = 0.4 V
Ios	Short Circuit Current (Note	2)	-40		-225	mA	V _{CC} = MAX	OB
	Davier Cumply Current	LS125A			20		JO MAN	$V_{IN} = 0 \text{ V}, V_{E} = 4.5 \text{ V}$
I _{CC}	Power Supply Current	LS126A			22	mA	$V_{CC} = MAX$	V _{IN} = 0 V, V _E = 0 V

^{2.} Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C)

				Limits	2 05	121		
Symbol	Parameter		Min	Тур	Max	Unit	Tes	st Conditions
t _{PLH}		LS125A		9.0	15),		
t _{PLH}	Propagation Delay,	LS126A		9.0	15	,,,	Figure 2	V_{CC} = 5.0 V C_L = 45 pF R_L = 667 Ω
t _{PHL}	Data to Output	LS125A		7.0	18	ns		
t _{PHL}		LS126A	7/ S.	8.0	18			
+	Output Enable Time	LS125A		12	20	ns	Figures 4, 5	
t _{PZH}	to HIGH Level	LS126A		16	25	115		
+	Output Enable Time	LS125A	S	15	25	200	Figures 3, 5	
t _{PZL}	to LOW Level	LS126A	0.	21	35	ns		
	Output Disable Time	LS125A			20		Figures 4 F	
t _{PHZ}	from HIGH Level	LS126A			25	ns	Figures 4, 5	V_{CC} = 5.0 V C_L = 5.0 pF R_L = 667 Ω
	Output Disable Time	LS125A			20	ns	ns Flgures 3, 5	
t _{PLZ}	from LOW Level	LS126A			25			



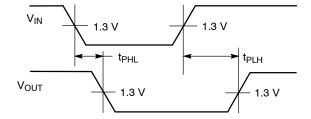
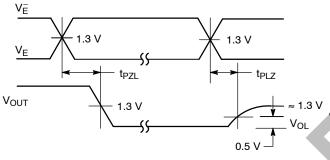


Figure 1.

Figure 2.



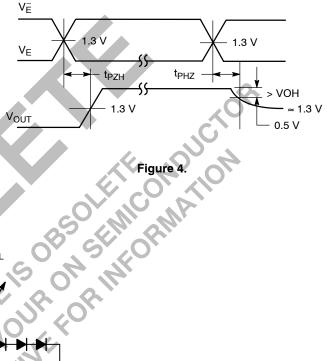


Figure 3.

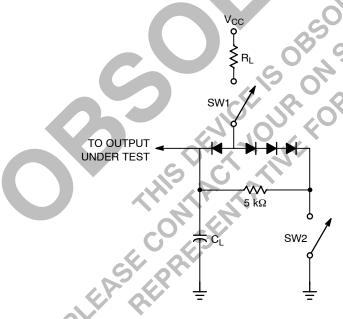


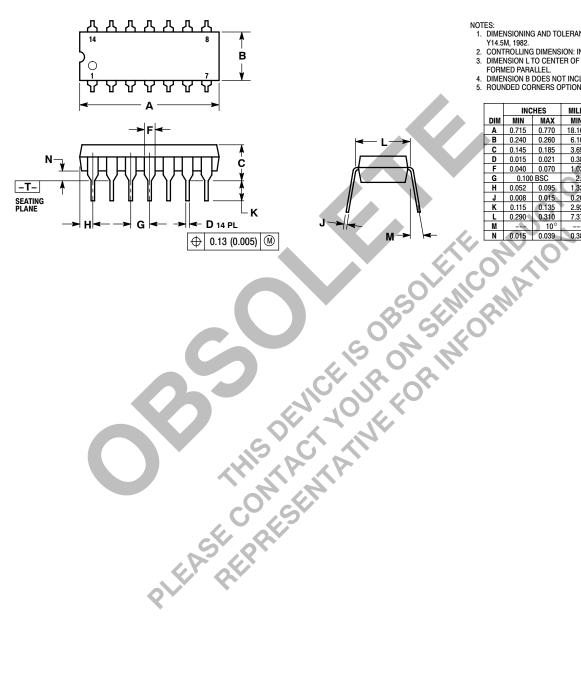
Figure 5.

SWITCH POSITIONS

SYMBOL	SW1	SW2
t _{PZH}	Open	Closed
t _{PZL}	Closed	Open
t _{PLZ}	Closed	Closed
t _{PHZ}	Closed	Closed

PACKAGE DIMENSIONS

N SUFFIX PLASTIC PACKAGE CASE 646-06 ISSUE M





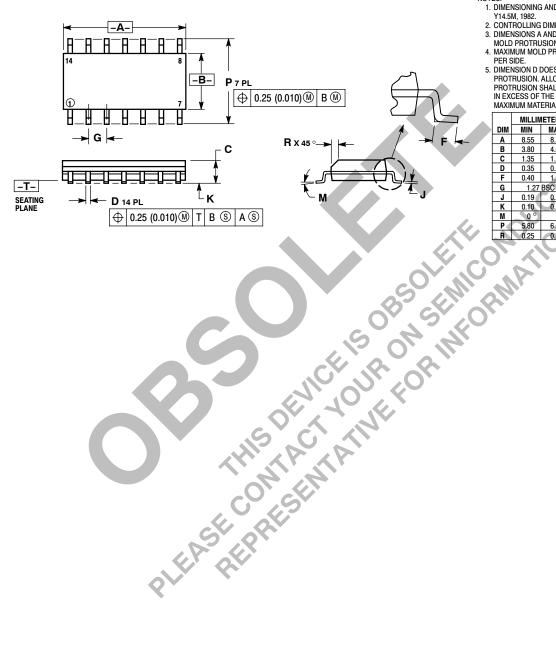
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS			
DIM	MIN	MAX	MIN	MAX			
Α	0.715	0.770	18.16	18.80			
В	0.240	0.260	6.10	6.60			
С	0.145	0.185	3.69	4.69			
D	0.015	0.021	0.38	0.53			
F	0.040	0.070	1.02	1.78			
G	0.100	BSC	2.54 BSC				
Н	0.052	0.095	1.32	2.41			
J	0.008	0.015	0.20	0.38			
K	0.115	0.135	2.92	3.43			
L	0.290	0.310	7.37	7.87			
M	-4	10°		10°			
N	0.015	0.039	0.38	1.01			

PACKAGE DIMENSIONS

D SUFFIX

PLASTIC SOIC PACKAGE CASE 751A-03 **ISSUE F**



NOTES:

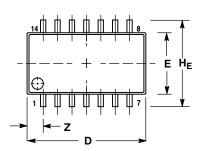
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE
 MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE.
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

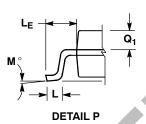
		MILLIN	IETERS	INC	HES
Þ	DIM	MIN	MAX	MIN	MAX
	Α	8.55	8.75	0.337	0.344
	В	3.80	4.00	0.150	0.157
	С	1.35	1.75	0.054	0.068
	D	0.35	0.49	0.014	0.019
	F	0.40	1.25	0.016	0.049
	G	1.27	BSC	0.050	BSC
	ſ	0.19	0.25	0.008	0.009
	K	0.10	0.25	0.004	0.009
	M	0°	7°	0°	7°
	P	5.80	6.20	0.228	0.244
	B	0.25	0.50	0.010	0.019

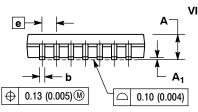
PACKAGE DIMENSIONS

M SUFFIX

SOEIAJ PACKAGE CASE 965-01 **ISSUE O**









- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	-	2.05		0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
C	0.18	0.27	0.007	0.011
a	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
е	1.27 BSC		0.050	BSC
HE	7.40	8.20	0.291	0.323
0.50	0.50	0.85	0.020	0.033
L _E	1.10	1.50	0.043	0.059
N	0 °	10°	0 °	10°
Q	0.70	0.90	0.028	0.035
Z		1.42		0.056

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